

# SS12 THRU SS110

## SURFACE MOUNT SCHOTTKY BARRIER RECTIFIER



康比電子  
HORNBY ELECTRONIC

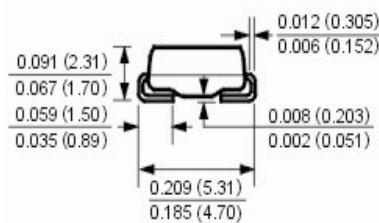
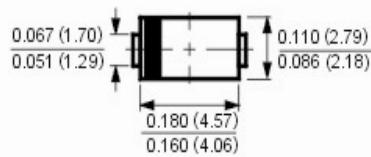
**REVERSE VOLTAGE:** 20 to 100 VOLTS

**FORWARD CURRENT:** 1.0 AMPERE

### FEATURES

- Plastic package has Underwriters Laboratory Flammability Classification 94V-O
- For surface mounted applications
- High current capacity
- Built-in strain relief
- Low profile package
- Metal to silicon rectifier, majority carrier conduction
- High surge capacity
- Low power loss, high efficiency
- For use in low voltage high frequency inverters, free wheeling, and polarity protection applications
- High temperature soldering : 250°C / 10 seconds at terminals

### DO-214AC(SMA)



### MECHANICAL DATA

Case: Molded plastic, DO-214AC(SMA)

Terminals: Solder plated, solderable per MIL-STD-750, method 2026 guaranteed

Polarity: Color band denotes cathode end

Packaging: 12mm tape per EIA STD RS-481

Weight: 0.002 ounce, 0.064 gram

### Dimensions in inches and (millimeters)

### Maximum Ratings and Electrical Characteristics

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitive load, derate current by 20%.

	Symbol	SS12	SS13	SS14	SS15	SS16	SS18	SS19	SS110	Units
<b>Maximum Recurrent Peak Reverse Voltage</b>	V <sub>RRM</sub>	20	30	40	50	60	80	90	100	Volts
<b>Maximum RMS Voltage</b>	V <sub>RMS</sub>	14	21	28	35	42	56	63	70	Volts
<b>Maximum DC Blocking Voltage</b>	V <sub>DC</sub>	20	30	40	50	60	80	90	100	Volts
<b>Maximum Average Forward Rectified Current at T<sub>L</sub> (See Fig. 1)</b>	I <sub>(AV)</sub>									Amp
<b>Peak Forward Surge Current, 8.3ms single half-sine-wave superimposed on rated load (JEDEC method)</b>	I <sub>FSM</sub>									Amp
<b>Maximum Forward Voltage at 1.0A (Note 1)</b>	V <sub>F</sub>		0.50		0.70		0.85			Volts
<b>Maximum Reverse Current at T<sub>A</sub>=25°C at Rated DC Blocking Voltage T<sub>A</sub>=100°C</b>	I <sub>R</sub>				0.5					mAmp
<b>Typical Thermal Resistance (Note 2)</b>	R <sub>θJA</sub> R <sub>θJL</sub>				20					°C/W
<b>Operating Junction Temperature Range</b>	T <sub>J</sub>				-55 to +125					°C
<b>Storage Temperature Range</b>	T <sub>stg</sub>				-55 to +150					°C

### NOTES:

1- Pulse test: 300μs pulse width, 1% duty cycle

2- P.C.B. mounted with 0.2 x 0.2" (5.0 x 5.0mm) Copper Pad Areas

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### RATINGS AND CHARACTERISTIC CURVES

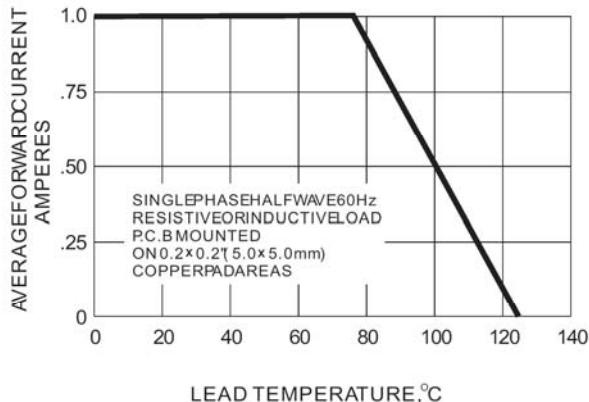


Fig.1-FORWARD CURRENT DERATING CURVE

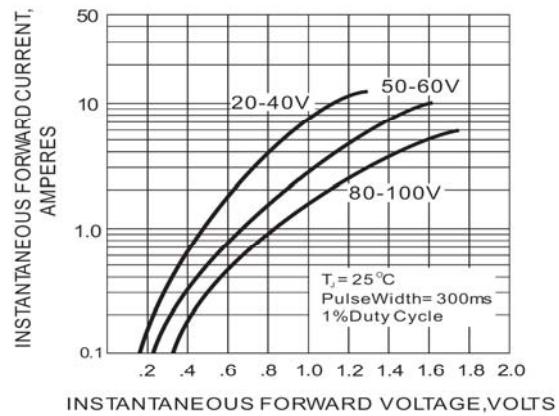


Fig.2-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTIC

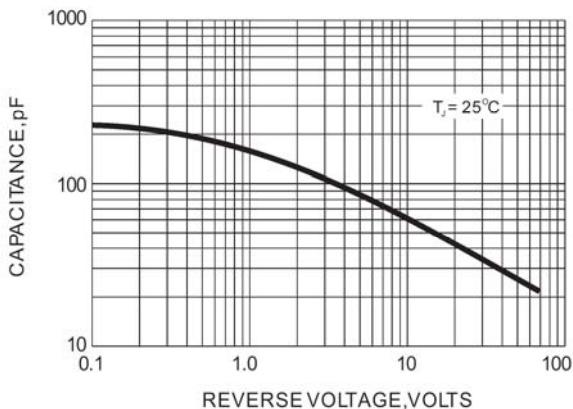


Fig.3-TYPICAL JUNCTION CAPACITANCE

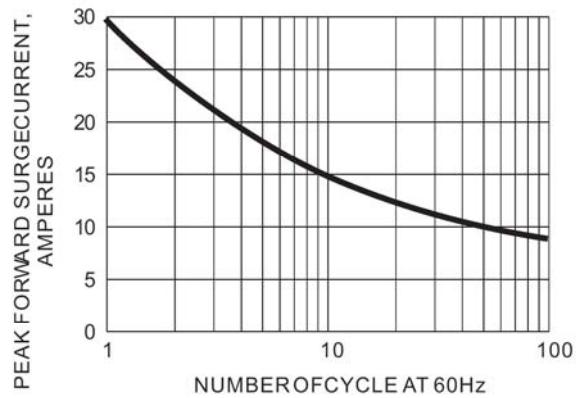


Fig.4-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT